

Gas Kinetics

Introduction

- Most deposition techniques rely on gas flow in a vacuum.
- We need a model for understanding;
 - the speed and energy of the gas molecules as a function of temperature and pressure,
 - how these molecules interact with each other and their surroundings,
 - and how mass, heat and momentum is transported by these molecules.

The Size of a Molecule

(a very rough calculation)

- Take water (liquid H₂O) as an example.
- Oxygen has 8 protons and 8 neutrons for a total of 16 nucleons and Hydrogen has 1 proton. So water has $16+1+1=18$ nucleons

$$m_P \approx m_N \approx 1.66 \times 10^{-24} \text{ g}$$

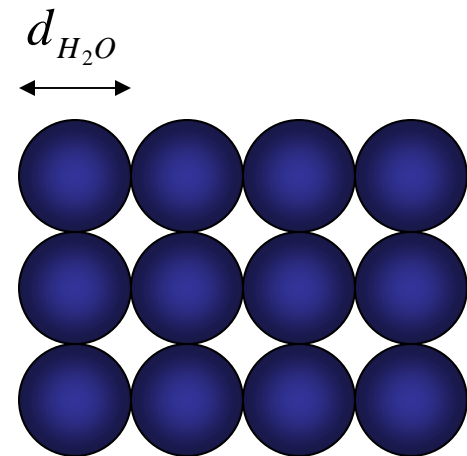
$$m_{H_2O} = 18m_N = 2.99 \times 10^{-23} \text{ g}$$

$$N_{H_2O} = 1/m_{H_2O} = 3.35 \times 10^{22} \text{ molecules / g}$$

$$\rho_{H_2O} = 1.00 \text{ g / cm}^3$$

$$V_{H_2O} = \frac{1}{\rho_{H_2O} N_{H_2O}} = 2.99 \times 10^{-23} \text{ cm}^3 / \text{molecule}$$

$$d_{H_2O} = 2 \times \sqrt[3]{\frac{3}{4} V_{H_2O}} = 5.64 \times 10^{-8} \text{ cm}$$



The Distance Between Molecules in a Gas

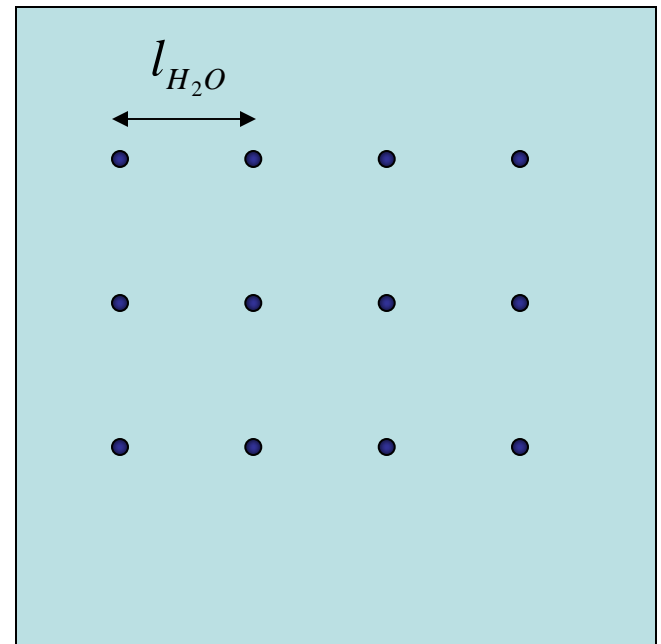
- Now take water vapor (gaseous H₂O).

$$\rho_{H_2O} = 0.8 \times 10^{-3} \text{ g / cm}^3$$

$$V_{H_2O} = \frac{1}{\rho_{H_2O} N_{H_2O}} = 3.73 \times 10^{-20} \text{ cm}^3 / \text{molecule}$$

$$l_{H_2O} = \sqrt[3]{V_{H_2O}} = 3.34 \times 10^{-7} \text{ cm}$$

$$l_{H_2O} \approx 6d_{H_2O}$$



Molecular Velocities

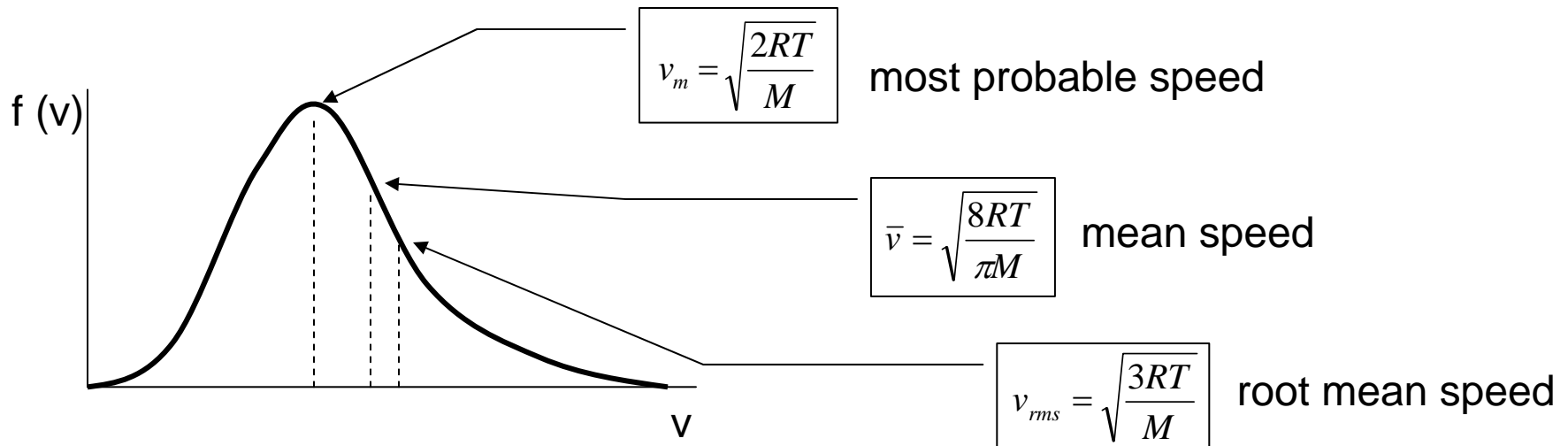
- Basic assumptions:
 - We'll assume an ideal gas where the gas molecules interact elastically (collisions are similar to the collisions of hard billiard balls).
 - The distance between molecules are large compared to their sizes.
 - There are no attractive or repulsive forces between the molecules and each molecule moves independently of the others.

Maxwell-Boltzmann Distribution

- Under these assumptions, the molecules of a gas have velocities that are distributed according to:

$$f(v) = \frac{1}{n} \frac{dn}{dv} = 4\pi v^2 \sqrt{\frac{M}{2\pi RT}} \exp\left(-\frac{Mv^2}{2RT}\right)$$

where f is the fractional number of molecules, v is the velocity, M is the molecular weight, T is the temperature and R is the universal gas constant.



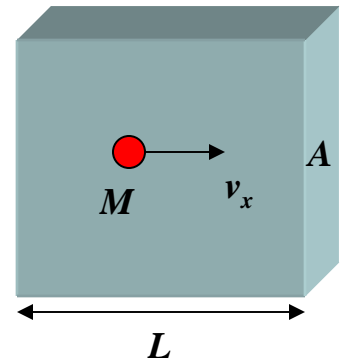
While the velocity of a single molecule depends on the temperature and its molecular weight, its kinetic energy is only dependent on temperature and is equally partitioned into the three coordinates.

Pressure

- Since readily measurable quantities are temperature and pressure (and not number density or velocity) we need a more convenient relationship that relates them.
- Pressure arises from the momentum transfer from the gas molecules to the walls of the container.
- The average force on the walls of the container is given by:

$$\bar{F} = MN_m \frac{\bar{v}_x^2}{L} = \frac{1}{3} MN_m \frac{\bar{v}^2}{L} = \frac{MN_m}{3L} \frac{3RT}{M} = \frac{N_m RT}{L} = \frac{N_m RTA}{V}$$

$$P = \frac{\bar{F}}{A} = \frac{N_m RT}{V} \quad \text{then}$$



$$\boxed{PV = N_m RT} \quad \text{or} \quad \boxed{PV = Nk_B T}$$

where N_m is the total number of moles of the gas and N is the number of molecules

Units of Pressure

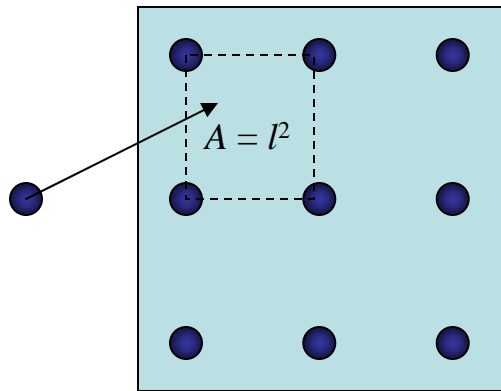
- SI units: 1 Pascal (1 Pa) = 1 N/m²
 - Not very practical
- 1 Torr = 133 Pa = 1 mm Hg
- 1 bar = 750 Torr = 10⁵ Pa = 0.987 atm
- 1 atm = 760 Torr = 10100 Pa
- 1 psi = 51.71 Torr = 0.068 atm

Mean Free Path

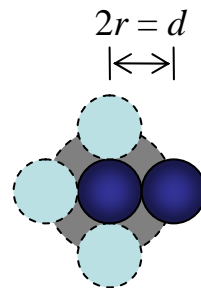
- In a vapor, gas molecules will be moving freely.
- Their motion is interrupted only by collisions with other molecules or the container.
- The average distance a molecule can move between collisions is called the mean free path.

Rough Calculation of the MFP

- Suppose there is a gas molecule trying to get through an array of gas molecules.



Area blocked by one molecule



Probability that a collision will occur

$$R = \pi d^2 / l^2$$

Average number of layers between collisions

$$1/2R = l^2 / 2\pi d^2$$

$$MFP = \frac{l}{2R} = \frac{l^3}{2\pi d^2} = \frac{1}{2\pi n d^2}$$

where n is the number of gas molecules per cm^3

Rough Calculation of the MFP

In an ideal gas $n = \frac{N}{V} = \frac{P}{k_B T}$

$$MFP = \frac{1}{2\pi n d^2} = \frac{k_B T}{2\pi d^2 P}$$

More accurately

$$MFP = \frac{\sqrt{2} k_B T}{2\pi d^2 P}$$

P (Torr)	MFP (cm)
760	10^{-5}
1	10^{-2}
0.001	10

Molecular Flow Regimes

- Since film deposition depends on how a gas flows and the mean free path is a measure of the interaction between the gas molecules, it determines the type of gas flow that can happen.
- The flow of gas is characterized by the **Knudsen number** (Kn).

$$Kn = \frac{MFP}{L}$$

L is a dimension of the vacuum chamber

- If $Kn < 0.01$, many molecules in chamber, pressure is high, the flow is viscous (like a fluid).
- If $Kn > 1$, few molecules in chamber, pressure is low, gas flow is molecular and ballistic.
- If $1 > Kn > 0.01$, the gas is in a transition regime where neither property is valid.

Gas Transport: Diffusion

- Diffusion in gases is the mixing of one material (A) into another (B).
- Fick's Law for solids is still valid.

$$J = -D \frac{dn_A}{dx}$$

$$D \propto \frac{T^{7/4} \sqrt{\frac{1}{M_A} + \frac{1}{M_B}}}{P(d_A + d_B)^2}$$

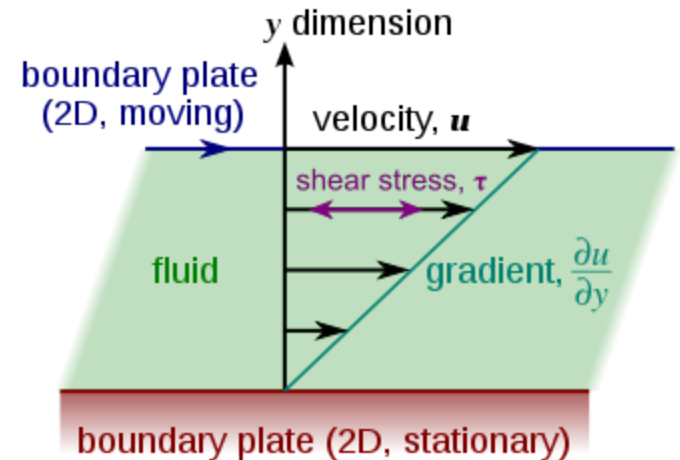
- In the ballistic regime ($Kn > 1$) diffusion will not occur (not enough molecules around).

Gas Transport: Viscosity

- In a chamber, gas molecules traveling at different speed exert drag on each other.

$$\tau = \eta \left(\frac{du}{dy} \right)$$

where, τ is the shear stress, u is the velocity in a direction perpendicular to y and η is the viscosity.



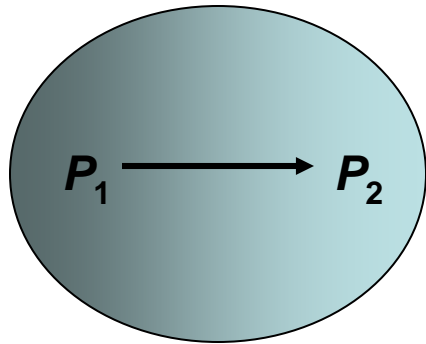
- Again, in the ballistic regime, viscous interactions do not occur.

Gas Transport: Heat Conduction

- Heat can be transported through the transfer of kinetic energy between gas molecules.
- In the viscous regime, heat transfer between a heater and the substrate occurs through the collisions of the gas molecules in between.
- In the ballistic regime, the molecules don't collide with each other so heat transfer depends on the amount of flow of molecules (flux) from the heater to the substrate.

Gas Flow

- Gas will flow when there is a pressure difference between different sections of a chamber.



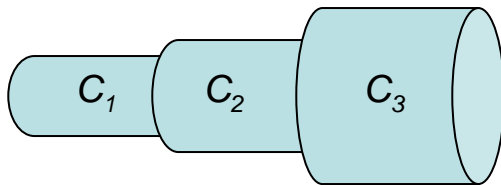
$$Q = C(P_1 - P_2)$$

Conductance (Lt/s) is
shape dependent

Throughput

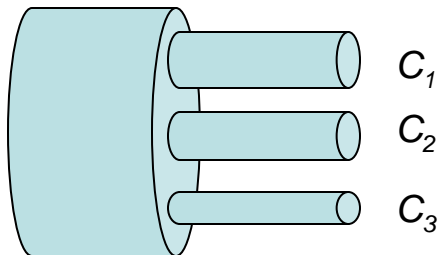
Conductance

- In a system with multiple components, the overall conductance is determined by how the components are hooked up.
- Series connections:



$$C_{sys} = \left(\frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3} + \dots \right)^{-1}$$

- Parallel connections:

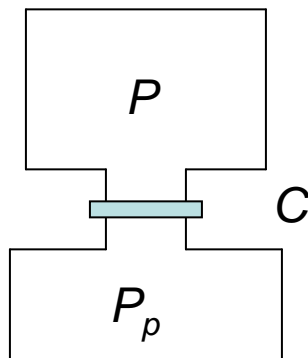


$$C_{sys} = C_1 + C_2 + C_3 + \dots$$

Pumping Speed

- The pumping speed S_p , is defined as the volume of gas passing the plane of the inlet port per unit time when the pressure at the pump inlet is P_p .

$$Q = P_p S_p$$



Chamber

$$Q = C(P - P_p) = P_p S_p$$

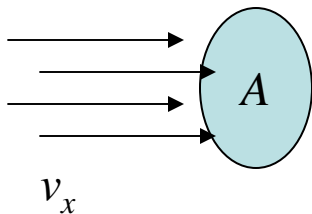
$$S_{eff} = \frac{Q}{P} = \frac{S_p}{1 + S_p/C}$$

Interaction With Surfaces

- Gas molecules colliding with the chamber walls result in pressure.
- Another possible interaction (and one crucial in film deposition) is gas impingement on other surfaces such as the substrate.
- A measure of the amount of gas incident on a surface is the flux.

Flux

- The flux is the number of molecules that strike an element of a surface perpendicular to a coordinate direction, per unit time and area.



$$\Phi = \int_0^{\infty} v_x dn_x \longrightarrow \frac{\Phi}{N_A} = \frac{P}{\sqrt{2\pi MRT}}$$

$$\Phi = 3.513 \times 10^{22} \frac{P}{\sqrt{MT}}$$

with P expressed in Torrs

Deposition Rate

- The flux of molecules on the surface leads to deposition where the rate of film growth depends on the flux.

$$\frac{dh_{film}}{dt} = \Phi \left(\frac{M_{film}}{\rho_{film} N_A} \right) \quad \text{where } M_{film} \text{ is the molar molecular mass (g/mol) and } \rho_{film} \text{ is the film density (g/m}^3\text{)}$$

- Of course this assumes that there are no chemical reactions, bouncing off of molecules or diffusion into the surface.